NSN 5961-01-055-2232

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-055-2232 **Inclosure Material:** Glass **Overall Length:** Between 0.130 inches and 0.260 inches **Terminal Length:** Between 0.900 inches and 1.300 inches **Overall Diameter:** Between 0.110 inches and 0.180 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-41 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 working peak reverse voltage **Current Rating Per Characteristic:** 80.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/411 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No